

## -30V/-7A P-Channel MOSFET

### Features

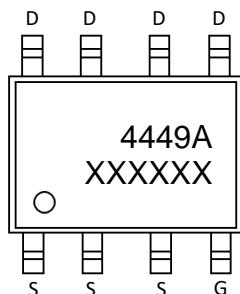
- Trench Power LV MOSFET technology
- High density cell design for Low  $R_{DS(ON)}$
- High Speed switching

### Product Summary

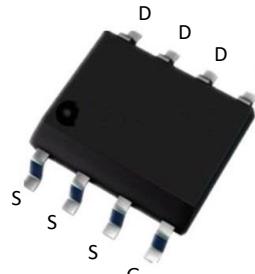
| $V_{DS}$ | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| -30V     | 34mΩ@10V                 | -7A               |
|          | 54mΩ@4.5V                |                   |

### Application

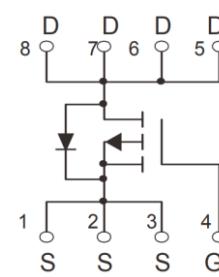
- Battery protection
- Power management
- Load switch



4449A : Device code  
XXXXXX : Code



SOP-8 top view



Schematic diagram

Marking and pin assignment

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

### Common Ratings (TC=25°C Unless Otherwise Noted)

|           |                                  |            |    |
|-----------|----------------------------------|------------|----|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | -30        | V  |
| $V_{GS}$  | Gate-Source Voltage              | ±20        | V  |
| $T_J$     | Maximum Junction Temperature     | 150        | °C |
| $T_{STG}$ | Storage Temperature Range        | -50 to 155 | °C |
| $I_S$     | Diode Continuous Forward Current | Tc=25°C    | -7 |
|           |                                  |            | A  |

### Mounted on Large Heat Sink

|           |  |         |     |      |
|-----------|--|---------|-----|------|
| $I_{DM}$  | Pulse Drain Current Tested   | Tc=25°C | -30 | A    |
| $I_D$     | Continuous Drain Current@GS=10V                                      | Tc=25°C | -7  | A    |
| $P_D$     | Maximum Power Dissipation  | Tc=25°C | 3   | W    |
| $R_{θJA}$ | Thermal Resistance Junction-Ambient(*1 in2 Pad of 2-oz Copper), Max. |         | 30  | °C/W |

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

| Symbol  | Parameter                        | Condition          | Min | Typ  | Max  | Unit |
|---|----------------------------------|--------------------|-----|------|------|------|
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |                    |     |      |      |      |
| BV <sub>(BR)DSS</sub>   | Drain-Source Breakdown Voltage   | VGS=0V, ID=-250µA  | -30 | --   | --   | V    |
| I <sub>DSS</sub>  | Zero Gate Voltage Drain Current  | VDS=-30V, VGS=0V   | --  | --   | -1   | uA   |
| I <sub>GSS</sub>  | Gate-Body Leakage Current        | VGS=±20V, VDS=0V   | --  | --   | ±100 | nA   |
| V <sub>GS(th)</sub>   | Gate Threshold Voltage           | VDS=VGS, ID=-250µA | -1  | -1.8 | -3   | V    |
| R <sub>DS(on)</sub>   | Drain-Source On-State Resistance | VGS=-10V, ID=-7A   | --  | 28   | 34   | mΩ   |
|   |                                  | VGS=-4.5V, ID=-5A  | --  | 47   | 54   |      |

**Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)**

|                  |                              |                             |    |     |    |    |
|------------------|------------------------------|-----------------------------|----|-----|----|----|
| C <sub>ISS</sub> | Input Capacitance            | VDS=-15V, VGS=0V,<br>f=1MHz | -- | 660 | -- | pF |
| C <sub>OSS</sub> | Output Capacitance           |                             | -- | 100 | -- | pF |
| C <sub>RSS</sub> | Reverse Transfer Capacitance |                             | -- | 64  | -- | pF |

**Switching Characteristics**

|                     |                     |                                      |    |     |    |    |
|---------------------|---------------------|--------------------------------------|----|-----|----|----|
| Q <sub>g</sub>      | Total Gate Charge   | VDS=-15V, ID=-7A,<br>VGS=-10V        | -- | 9.3 | -- | nC |
| Q <sub>gs</sub>     | Gate Source Charge  |                                      | -- | 1.5 | -- | nC |
| Q <sub>gd</sub>     | Gate Drain Charge   |                                      | -- | 2.2 | -- | nC |
| t <sub>d(on)</sub>  | Turn-on Delay Time  | VDD=-15V, ID=-7A,<br>VGS=-10V, RG=3Ω | -- | 7.5 | -- | nS |
| t <sub>r</sub>      | Turn-on Rise Time   |                                      | -- | 5.5 | -- | nS |
| t <sub>d(off)</sub> | Turn-Off Delay Time |                                      | -- | 20  | -- | nS |
| t <sub>f</sub>      | Turn-Off Fall Time  |                                      | -- | 8   | -- | nS |

**Source- Drain Diode Characteristics**

|                 |                    |  |    |      |      |   |
|-----------------|--------------------|--|----|------|------|---|
| V <sub>SD</sub> | Forward on voltage | T <sub>J</sub> =25°C, I <sub>S</sub> =-7A, | -- | -0.8 | -1.2 | V |
|-----------------|--------------------|--|----|------|------|---|

## Typical Operating Characteristics

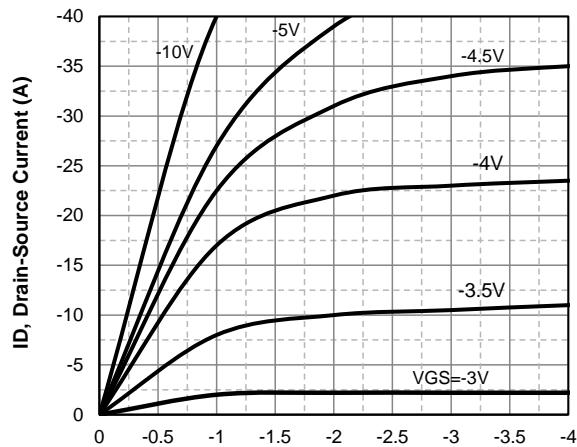


Fig1. Typical Output Characteristics

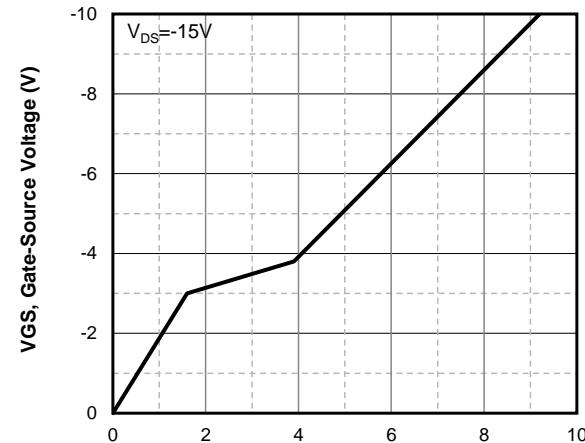


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

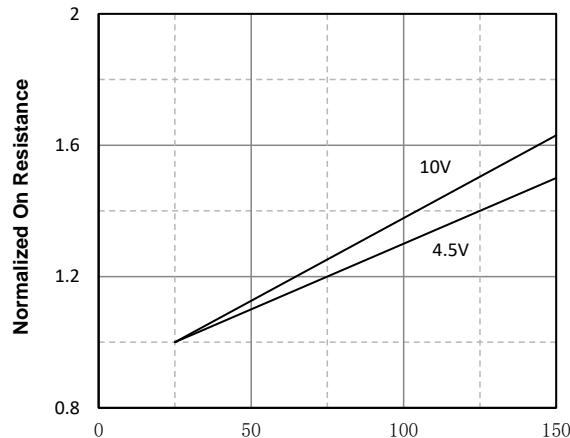


Fig3. Normalized On-Resistance Vs. Temperature

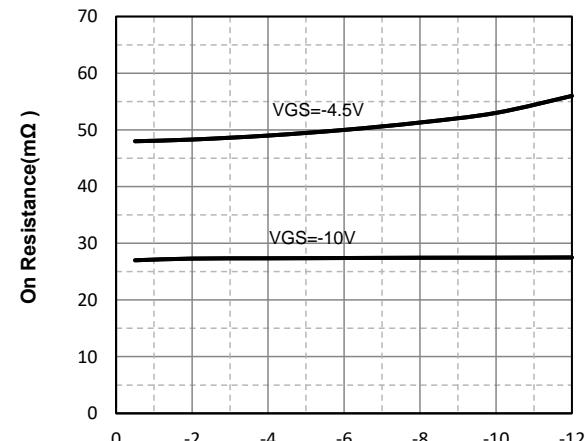


Fig4. On-Resistance Vs. Drain-Source Current

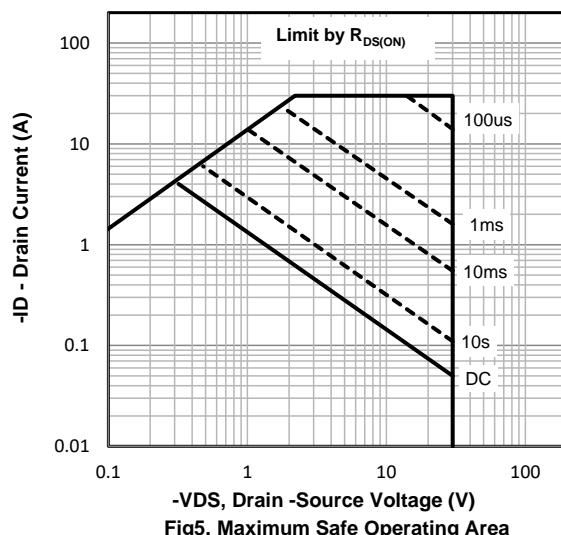


Fig5. Maximum Safe Operating Area

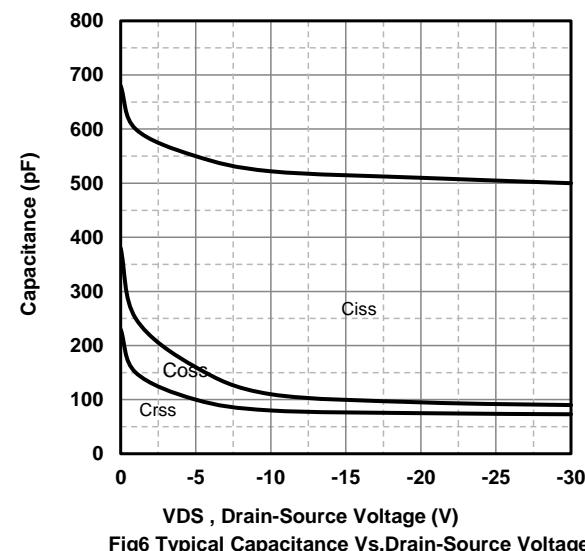
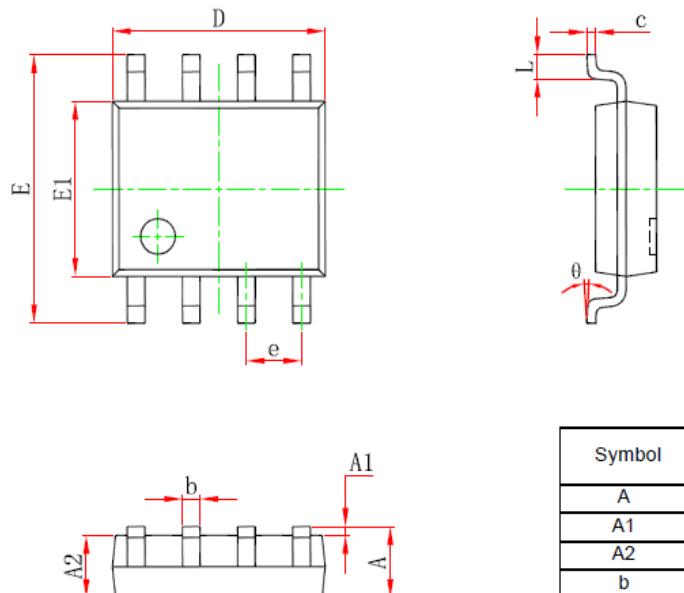


Fig6. Typical Capacitance Vs.Drain-Source Voltage

## SOP-8 Package information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 1.450                     | 1.750 | 0.053                | 0.069 |
| A1     | 0.100                     | 0.250 | 0.004                | 0.010 |
| A2     | 1.350                     | 1.550 | 0.053                | 0.061 |
| b      | 0.330                     | 0.510 | 0.013                | 0.020 |
| c      | 0.170                     | 0.250 | 0.007                | 0.010 |
| D      | 4.700                     | 5.100 | 0.185                | 0.201 |
| e      | 1.270 (BSC)               |       | 0.050 (BSC)          |       |
| E      | 5.800                     | 6.200 | 0.228                | 0.244 |
| E1     | 3.800                     | 4.000 | 0.150                | 0.157 |
| L      | 0.400                     | 1.270 | 0.016                | 0.050 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |